TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

SSM3K303T

High Speed Switching Applications

4 V drive

• Low ON-resistance: $R_{on} = 120 \text{ m}\Omega \text{ (max) (@V_{GS} = 4V)}$

 $R_{on} = 83 \text{ m}\Omega \text{ (max) (@V_{GS} = 10V)}$

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
Drain-source voltage		V_{DS}	30	V	
Gate-source voltage		V _{GSS}	± 20	V	
Drain current	DC	ID	2.9	А	
	Pulse	I _{DP}	5.8		
Drain power dissipation		P _D (Note 1)	700	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

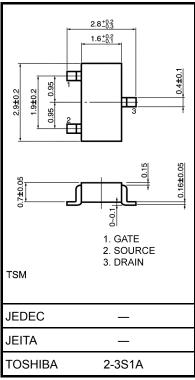
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual

reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Mounted on an FR4 board. (25.4 mm \times 25.4 mm \times 1.6 t, Cu Pad: 645 mm 2)

Unit: mm



Weight: 10 mg (typ.)

Electrical Characteristics (Ta = 25°C)

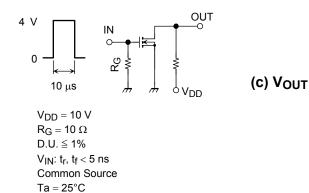
Charac	teristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Drain-source brea	ıkdown voltage	V (BR) DSS	$I_D = 1 \text{ mA}, V_{GS} = 0$	30	_	_	V
Drain cutoff currer	ıt	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0	_	_	1	μА
Gate leakage curre	ent	I _{GSS}	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$	_	_	±1	μА
Gate threshold vol	tage	V_{th}	V _{DS} = 5 V, I _D = 1 mA	1.1	_	2.6	V
Forward transfer a	dmittance	Y _{fs}	$V_{DS} = 5 \text{ V}, I_D = 1.5 \text{ A}$ (Note:	2) 2.5	4.9	_	S
Drain-source ON-resistance		R _{DS} (ON)	I _D = 1.5 A, V _{GS} = 10 V (Note:	2) —	64	83	mΩ
			I _D = 1.0 A, V _{GS} = 4 V (Note:	2) —	88	120	
Input capacitance		C _{iss}	V _{DS} = 10 V, V _{GS} = 0, f = 1 MHz	_	180	_	pF
Output capacitanc	е	Coss	V _{DS} = 10 V, V _{GS} = 0, f = 1 MHz	_	100	_	pF
Reverse transfer of	apacitance	C _{rss}	V _{DS} = 10 V, V _{GS} = 0, f = 1 MHz	_	38	_	pF
Total Gate Charge Gate–Source Charge Gate–Drain Charge		Q_g	V _{DS} = 15 V, I _{DS} = 2.9 A V _{GS} = 4 V	_	3.3	—	nC
		Q_{gs}		_	1.4	—	
		Q_{gd}		_	1.9	_	
Switching time	Turn-on time	t _{on}	V _{DD} = 10 V, I _D = 1.5 A,	_	13	_	
	Turn-off time	t _{off}	$V_{GS} = 0$ to 4 V, $R_G = 10 \Omega$	_	14	_	ns
Drain–source forward voltage		V _{DSF}	$I_D = -2.9 \text{ A}, V_{GS} = 0 \text{ V}$ (Note	2)	- 0.9	- 1.25	V

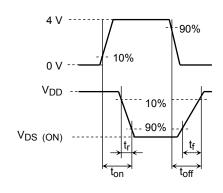
Note2: Pulse test

Switching Time Test Circuit

(a) Test Circuit

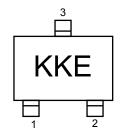


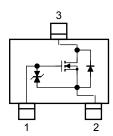




Marking

Equivalent Circuit (top view)





Precaution

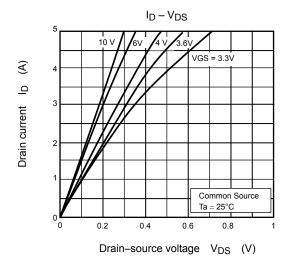
 V_{th} can be expressed as the voltage between gate and source when the low operating current value is I_D = 1 mA for this product. For normal switching operation, V_{GS} (on) requires a higher voltage than V_{th} and V_{GS} (off) requires a lower voltage than V_{th} .

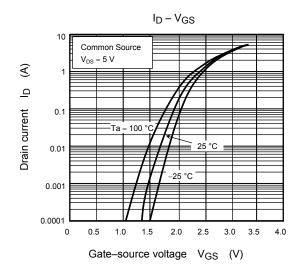
(The relationship can be established as follows: $V_{GS (off)} < V_{th} < V_{GS (on)}$.)

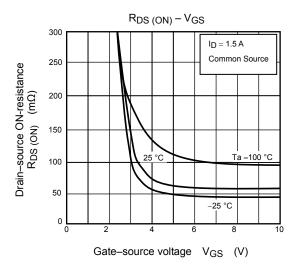
Take this into consideration when using the device.

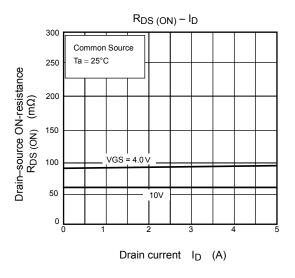
Handling Precaution

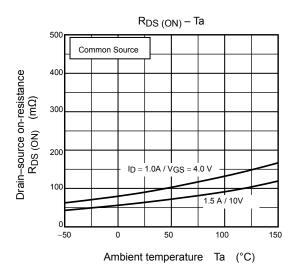
When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

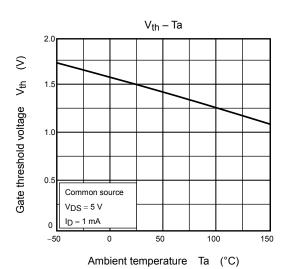




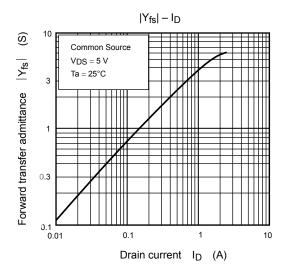


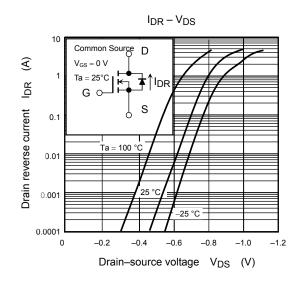


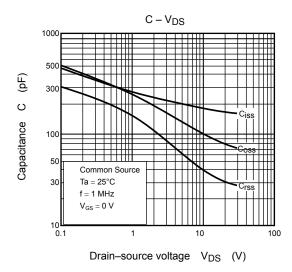


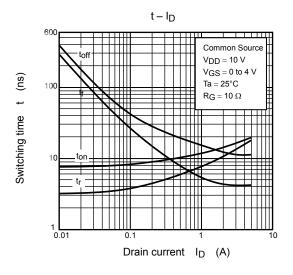


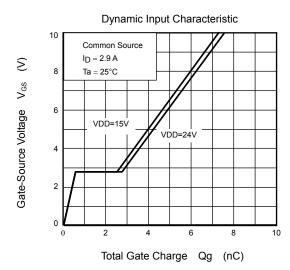
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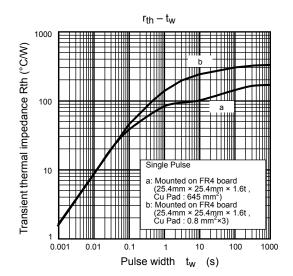


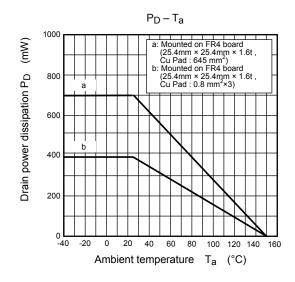






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20070701-EN GENERAL

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